

COMPLIANT

HALOGEN

FREE

Ultrafast Rectifier, 2 x 3 A FRED Pt®





PRIMARY CHARACTERIS

 $I_{F(AV)}$

 V_{R}

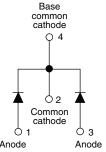
V_F at I_F

t_{rr} typ.

T_J max.

Package

Circuit configuration



\circ 1	\circ 3
Anode	Anode
STICS	
	2 x 3 A
	200 V
	0.9 V
See R	ecovery table

175 °C

DPAK (TO-252AA)

Common cathode

FEATURES

- · Ultrafast recovery time
- · Low forward voltage drop
- · Low leakage current
- 175 °C operating junction temperature
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

DESCRIPTION / APPLICATIONS

VS-MURD620CTHM3 is the state of the art ultrafast recovery rectifier specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, quarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Peak repetitive reverse voltage	V_{RRM}		200	V			
Average rectified forward current per device	I _{F(AV)}	Total device, rated V _R , T _C = 146 °C	6				
Non-repetitive peak surge current	I _{FSM}		50	Α			
Peak repetitive forward current per diode	I _{FM}	Rated V _R , square wave, 20 kHz, T _C = 146 °C	6				
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ	200	-	-		
Forward voltage	V _F	I _F = 3 A	-	0.9	1.0	V	
		I _F = 3 A, T _J = 125 °C	-	0.78	0.96		
		I _F = 6 A	-	1	1.2		
		I _F = 6 A, T _J = 125 °C	1	0.89	1.13		
Poverse leekage ourrent	I _R	$V_R = V_R$ rated	ı	-	5		
Reverse leakage current		$T_J = 125 ^{\circ}\text{C}, V_R = V_R \text{rated}$	-	-	250	μΑ	
Junction capacitance	C _T	V _R = 200 V	1	12	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nΗ	





DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	20	35		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	19	-	ns - A	
		T _J = 125 °C	I _F = 3 A dI _F /dt = 200 A/μs V _R = 160 V	-	26	-		
Peak recovery current	I _{RRM}	T _J = 25 °C		-	3.1	-		
		T _J = 125 °C		-	4.6	-		
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	30	-	nC	
		T _J = 125 °C		=	60	-		

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C
Thermal resistance, junction to case per leg	R _{thJC}		-	-	9.0	
Thermal resistance, junction to ambient per leg	R _{thJA}		-	-	80	°C/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	-	-	
Weight			-	0.3	-	g
vveigni			-	0.01	-	OZ.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style DPAK (TO-252AA)	MURD620CTH			

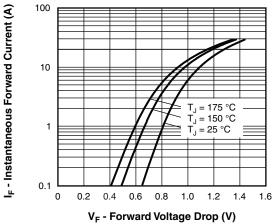


Fig. 1 - Typical Forward Voltage Drop Characteristics

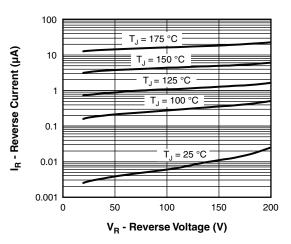


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

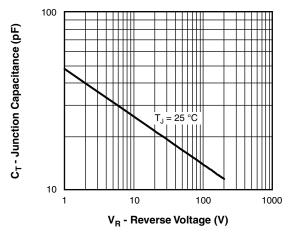


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

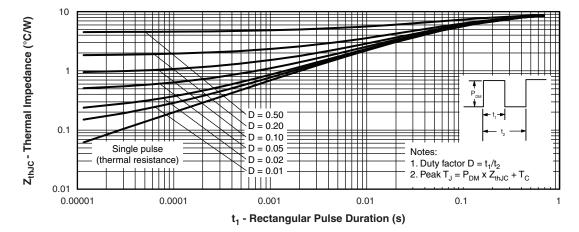


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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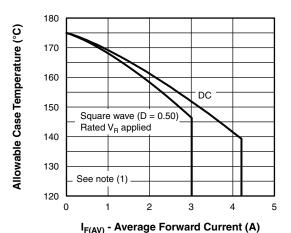


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

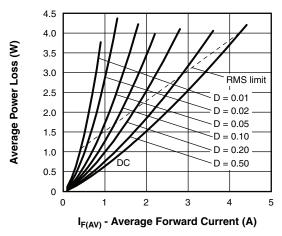


Fig. 6 - Forward Power Loss Characteristics

Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$

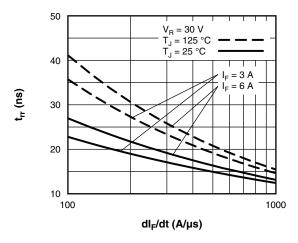


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

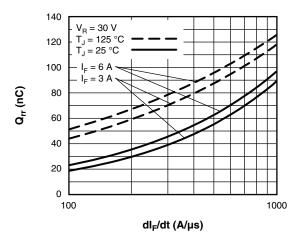


Fig. 8 - Typical Stored Charge vs. dl_F/dt



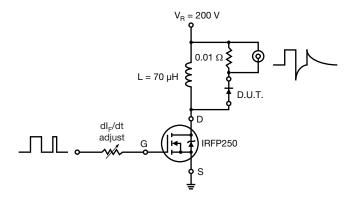
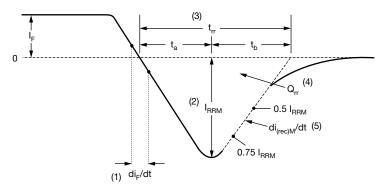


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

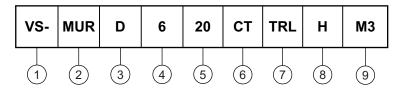
(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Ultrafast MUR series

3 - D = DPAK

Current rating (6 = 6 A)

Voltage rating (20 = 200 V)

- CT = center tap (dual) TR = tape and reel

TRL = tape and reel (left oriented)
TRR = tape and reel (right oriented)

8 - H = AEC-Q101 qualified

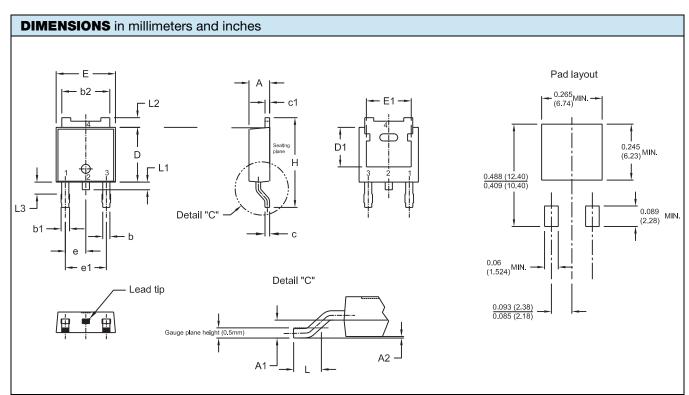
Environmental digit:
 M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-MURD620CTHM3	75	3000	Antistatic plastic tube				
VS-MURD620CTTRHM3	2000	2000	13" diameter reel				
VS-MURD620CTTRLHM3	3000	3000	13" diameter reel				
VS-MURD620CTTRRHM3	3000	3000	13" diameter reel				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95519				
Part marking information	www.vishay.com/doc?95518				
Packaging information	www.vishay.com/doc?95033				



D-PAK (TO-252AA)



SYMBOL	MILLIMETERS		INCHES		NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.21	2.38	0.087	0.094	
A2	0.03	0.127	0.001	0.005	
b	0.71	0.88	0.028	0.035	
b1	0.76	1.14	0.030	0.045	
b2	5.23	5.44	0.206	0.214	
С	0.46	0.58	0.018	0.023	
C1	0.46	0.58	0.018	0.023	
D	5.97	6.22	0.235	0.2455	
D1	4.32	4.45	0.170	0.175	
Е	6.48	6.73	0.255	0.2655	
E1	4.49	5.50	0.177	0.217	

SYMBOL	MROI		INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
A1	0.89	1.14	0.035	0.045	
Н	9.65	10.41	0.380	0.410	
L	1.40	1.78	0.055	0.070	
е	2.28 BSC		0.09 BSC		
e1	4.57 BSC		0.18 BSC		
L1	0.64	1.02	0.025	0.040	
L2	0.89	1.27	0.035	0.050	
L3	1.15	1.52	0.040	0.060	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L3 only for reference
- Dimension D1, E1, L2 and b2 establish a minimum mounting surface for thermal pad
- (4) Dimensions D and E do not include mold flash.
- (5) Outline conforms to JEDEC outline TO-252AA



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